

4 PIN DIP PHOTOTRANSISTOR AC INPUT PHOTOCOUPLER

EL814 Series

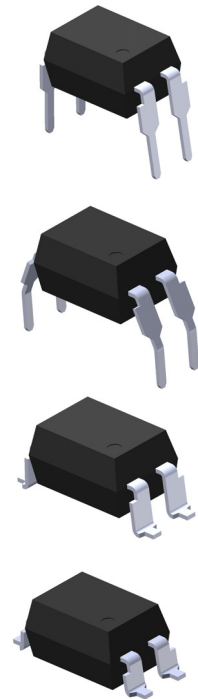
Features:

- AC input response
- Current transfer ratio
(CTR: Min. 20% at $I_F = \pm 1\text{mA}$, $V_{CE} = 5\text{V}$)
- High isolation voltage between input and output ($V_{iso} = 5000\text{ V rms}$)
- Wide Operating temperature range
-55~110°C
- High collector-emitter voltage $V_{CEO} = 80\text{V}$
- Compact dual-in-line package
- Pb free and RoHS compliant.
- UL approved (No. E214129)
- VDE approved (No. 132249)
- SEMKO approved
- NEMKO approved
- DEMKO approved
- FIMKO approved
- CSA approved
- CQC approved

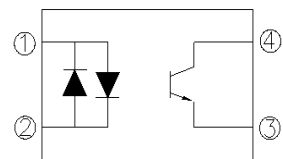
Description

The EL814 series of devices each consist of two infrared emitting diodes, connected in inverse parallel, optically coupled to a phototransistor detector.

They are packaged in a 4-pin DIP package and available in wide-lead spacing and SMD option.



Schematic



Pin Configuration

1. Anode / Cathode
2. Cathode / Anode
3. Emitter
4. Collector



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EL814 Series

Absolute Maximum Ratings ($T_a=25^{\circ}\text{C}$)

Parameter		Symbol	Rating	Unit
Input	Forward current	I_F	± 60	mA
	Peak forward current ($t = 10\mu\text{s}$)	I_{FM}	1	A
	Power dissipation	P_D	100	mW
	Derating factor (above 100°C)		2.9	mW/ $^{\circ}\text{C}$
Output	Power dissipation	P_C	150	mW
	Derating factor (above 100°C)		5.8	mW/ $^{\circ}\text{C}$
	Collector-Emitter voltage	V_{CEO}	80	V
	Emitter-Collector voltage	V_{ECO}	6	V
Total power dissipation		P_{tot}	200	mW
Isolation voltage ^{*1}		V_{iso}	5000	V rms
Operating temperature		T_{opr}	$-55\sim+110$	$^{\circ}\text{C}$
Storage temperature		T_{stg}	$-55\sim+125$	$^{\circ}\text{C}$
Soldering temperature ^{*2}		T_{sol}	260	$^{\circ}\text{C}$

Notes

*1 AC for 1 minute, R.H.= 40 ~ 60% R.H. In this test, pins 1 & 2 are shorted together, and pins 3 & 4 are shorted together.

*2 For 10 seconds.

4 PIN DIP PHOTOTRANSISTOR AC INPUT PHOTOCOUPLER

EL814 Series

Electrical Characteristics ($T_a=25^{\circ}\text{C}$ unless specified otherwise)

Input

Parameter	Symbol	Min.	Typ.*	Max.	Unit	Condition
Forward voltage	V_F	-	1.2	1.4	V	$I_F = \pm 20\text{mA}$
Input capacitance	C_{in}	-	50	250	pF	$V = 0, f = 1\text{KHz}$

Output

Parameter	Symbol	Min.	Typ.*	Max.	Unit	Condition
Collector-Emitter dark current	I_{CEO}	-	-	100	nA	$V_{CE} = 20\text{V}, I_F = 0\text{mA}$
Collector-Emitter breakdown voltage	BV_{CEO}	80	-	-	V	$I_C = 0.1\text{mA}$
Emitter-Collector breakdown voltage	BV_{ECO}	6	-	-	V	$I_E = 0.1\text{mA}$

Transfer Characteristics ($T_a=25^{\circ}\text{C}$ unless specified otherwise)

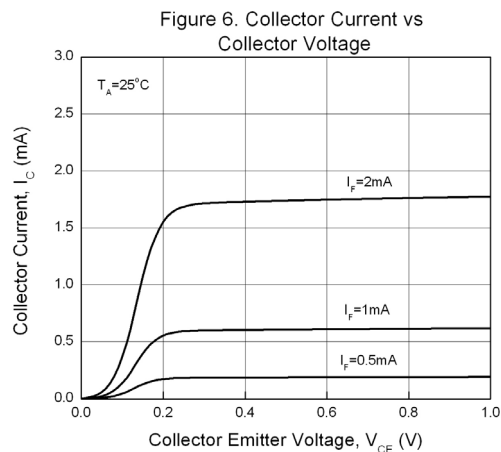
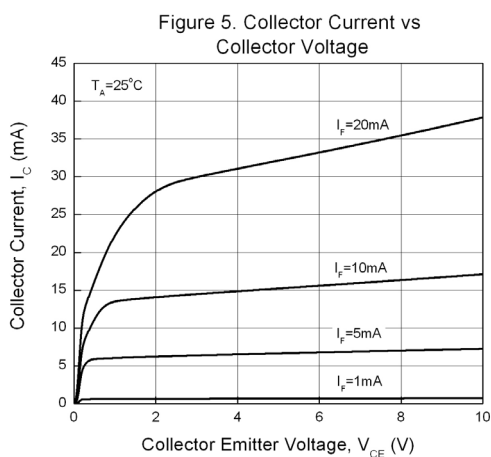
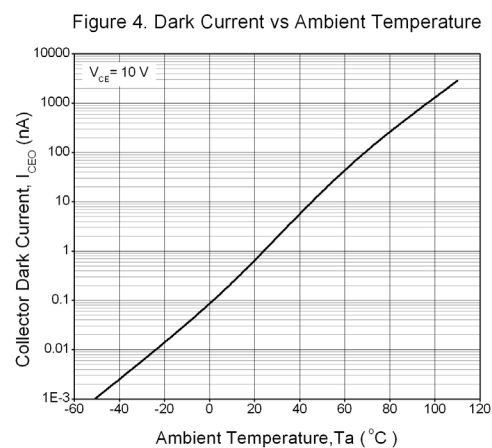
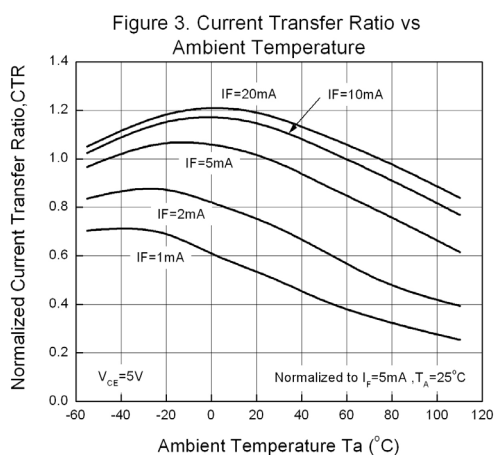
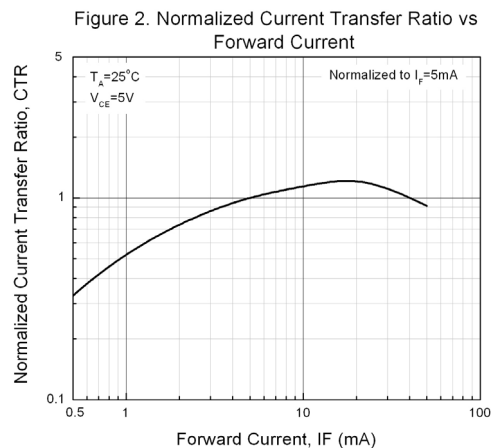
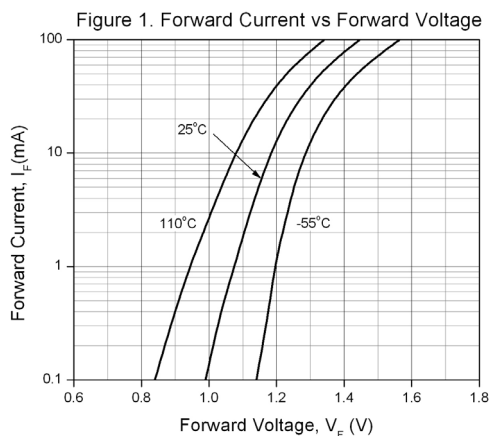
Parameter	Symbol	Min.	Typ.*	Max.	Unit	Condition
Current Transfer ratio	EL814	20	-	300	%	$I_F = \pm 1\text{mA}, V_{CE} = 5\text{V}$
	EL814A	50	-	150		
CTR Symmetry		0.7		1.3		$I_F = \pm 1\text{mA}, V_{CE} = 5\text{V}$
Collector-emitter saturation voltage	$V_{CE(sat)}$	-	0.05	0.2	V	$I_F = \pm 20\text{mA}, I_C = 1\text{mA}$
Isolation resistance	R_{IO}	5×10^{10}	10^{11}	-	Ω	$V_{IO} = 500\text{Vdc}, 40\% \text{ RH}$
Cut-off frequency	f_c	-	80	-	kHz	$V_{CE}=5\text{V}, I_C=2\text{mA}, R_L=100\Omega, -3\text{dB}$
Floating capacitance	C_{IO}	-	0.6	1.0	pF	$V_{IO} = 0, f = 1\text{MHz}$
Rise time	T_r	-	7	18	μs	$V_{CE}=2\text{V}, I_C=2\text{mA}, R_L=100\Omega$
Fall time	T_f	-	11	18	μs	

* Typical values at $T_a = 25^{\circ}\text{C}$

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EL814 Series

Typical Performance Curves



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EL814 Series

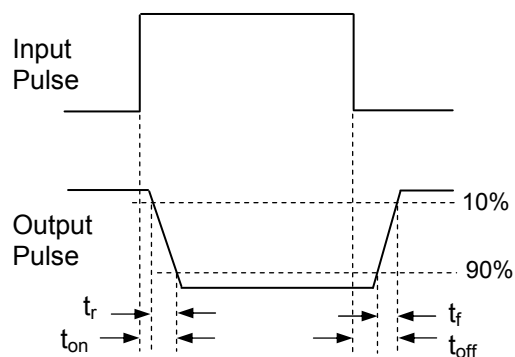
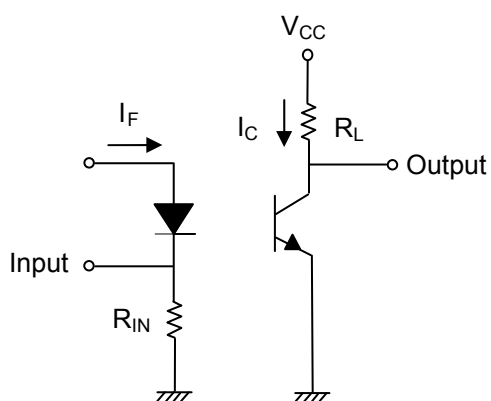
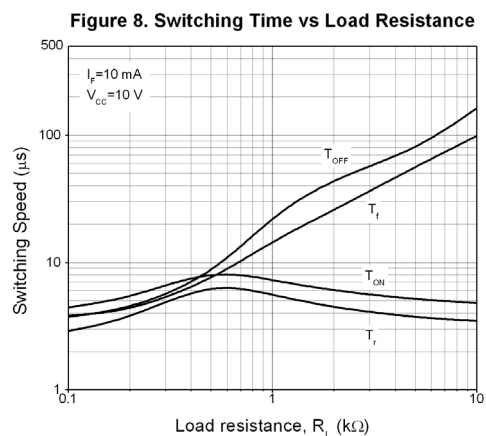
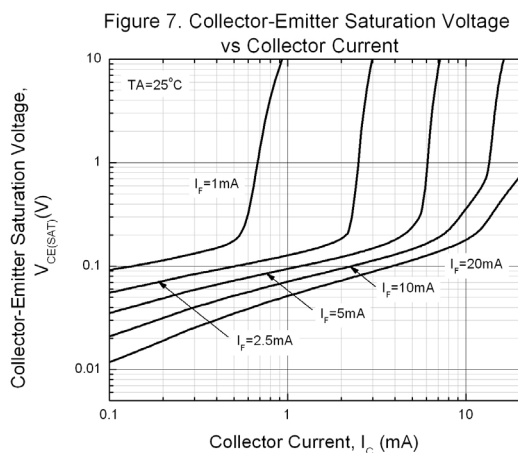


Figure 9. Switching Time Test Circuit & Waveforms



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4 PIN DIP PHOTOTRANSISTOR AC INPUT PHOTOCOUPLER

EL814 Series

Order Information

Part Number

EL814X(Y)(Z)-V

Note

- X = Lead form option (S, S1, M or none)
Y = CTR Rank option (A or none)
Z = Tape and reel option (TA, TB, TU, TD or none)
V = VDE safety (optional).

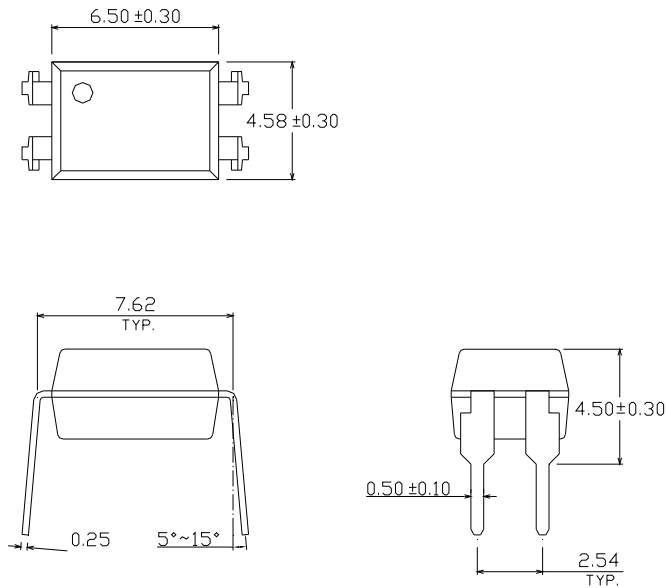
Option	Description	Packing quantity
None	Standard DIP-4	100 units per tube
M	Wide lead bend (0.4 inch spacing)	100 units per tube
S (TA)	Surface mount lead form + TA tape & reel option	1000 units per reel
S (TB)	Surface mount lead form + TB tape & reel option	1000 units per reel
S1 (TA)	Surface mount lead form (low profile) + TA tape & reel option	1000 units per reel
S1 (TB)	Surface mount lead form (low profile) + TB tape & reel option	1000 units per reel
S (TU)	Surface mount lead form + TU tape & reel option	1500 units per reel
S (TD)	Surface mount lead form + TD tape & reel option	1500 units per reel
S1 (TU)	Surface mount lead form (low profile) + TU tape & reel option	1500 units per reel
S1 (TD)	Surface mount lead form (low profile) + TD tape & reel option	1500 units per reel

4 PIN DIP PHOTOTRANSISTOR AC INPUT PHOTOCOUPLER

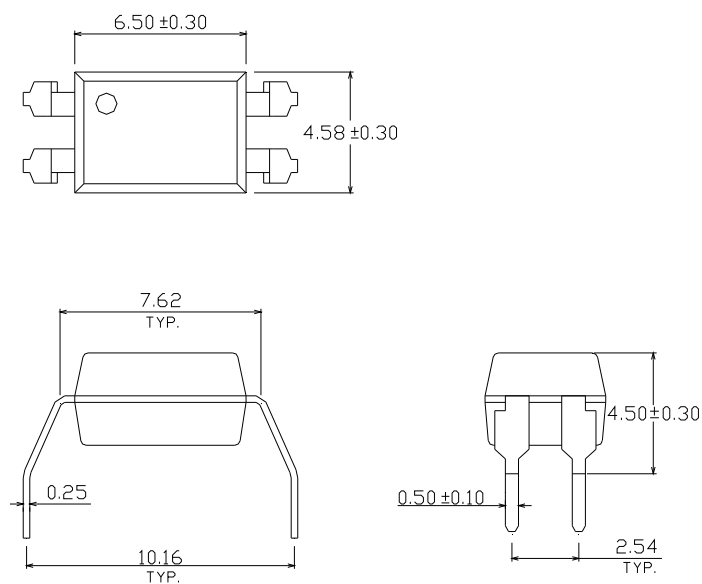
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Package Drawings (Dimensions in mm)

Standard DIP Type



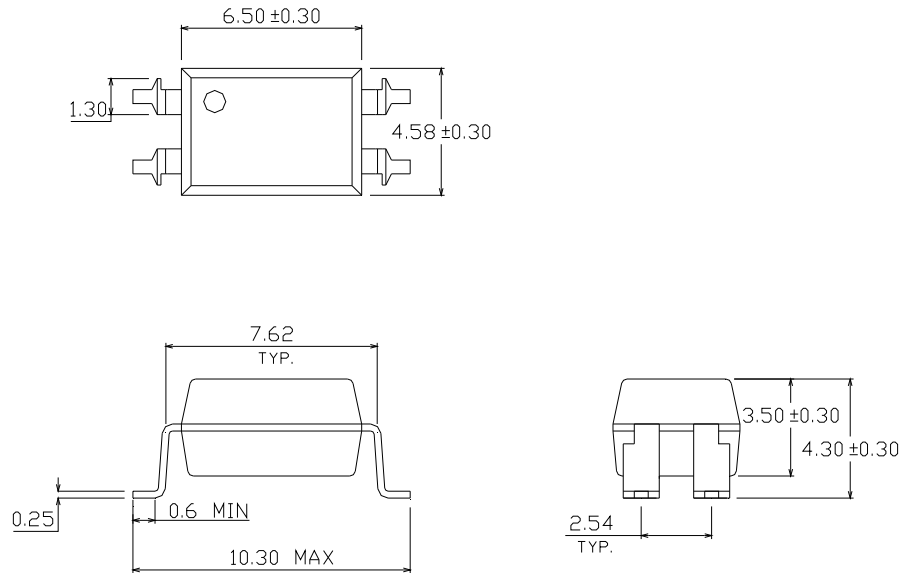
Option M Type



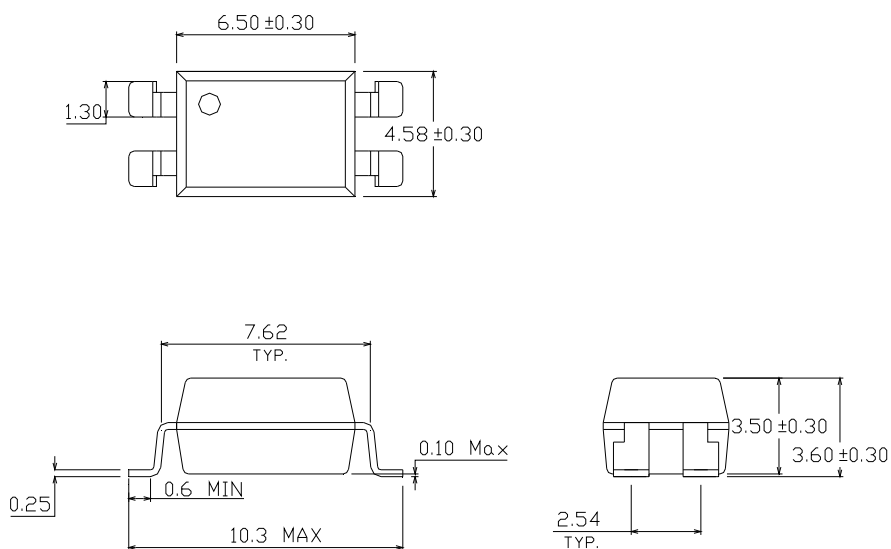
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Option S Type



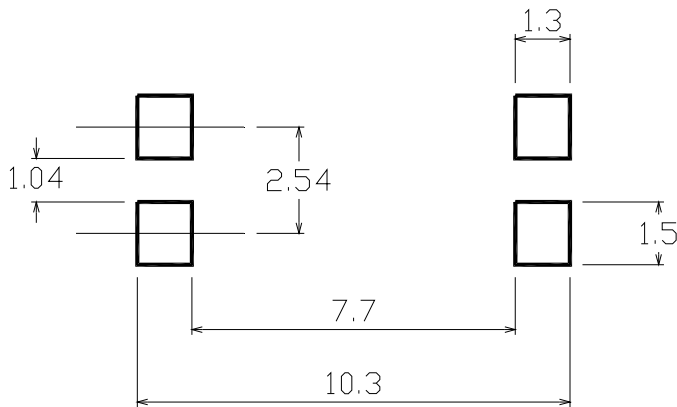
Option S1 Type



4 PIN DIP PHOTOTRANSISTOR AC INPUT PHOTOCOUPLER

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Recommended pad layout for surface mount leadform



Device Marking



Notes

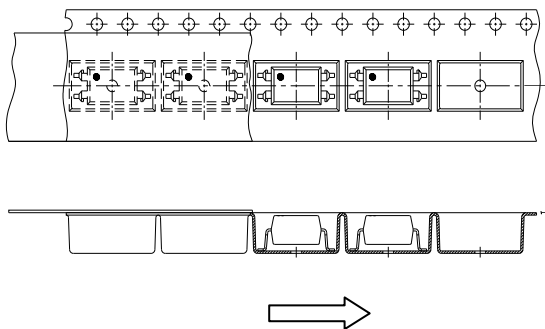
EL	denotes EVERLIGHT
814	denotes Device Number
F	denotes Factory Code (None: China, T: Taiwan)
R	denotes CTR Rank (A or none)
Y	denotes 1 digit Year code
WW	denotes 2 digit Week code
V	denotes VDE (optional)

4 PIN DIP PHOTOTRANSISTOR AC INPUT PHOTOCOUPLER

EL814 Series

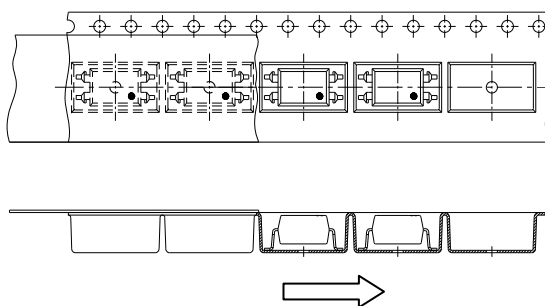
Tape & Reel Packing Specifications

Option TA



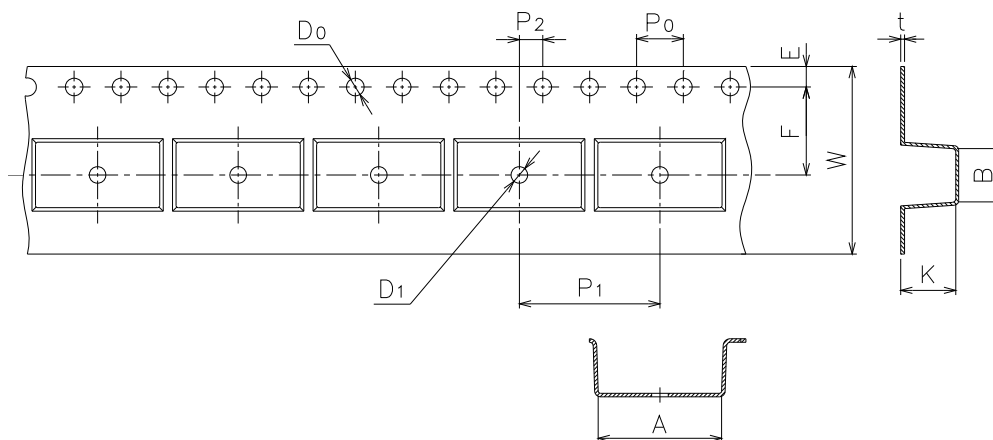
Direction of feed from reel

Option TB



Direction of feed from reel

Tape dimensions

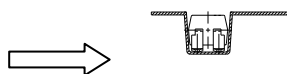
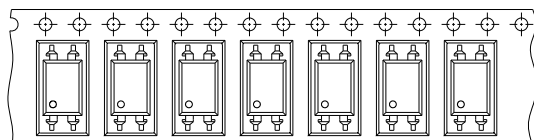


Dimension No.	A	B	Do	D1	E	F
Dimension(mm)	10.4±0.1	4.55±0.1	1.5±0.1	1.5±0.05	1.75±0.1	7.5±0.1
Dimension No.	Po	P1	P2	t	W	K
Dimension(mm)	4.0±0.1	12.0±0.1	2.0±0.1	0.33±0.1	16.0+0.3/ -0.1	4.55±0.1

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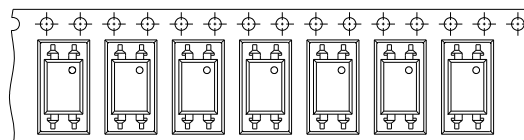
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Option TD



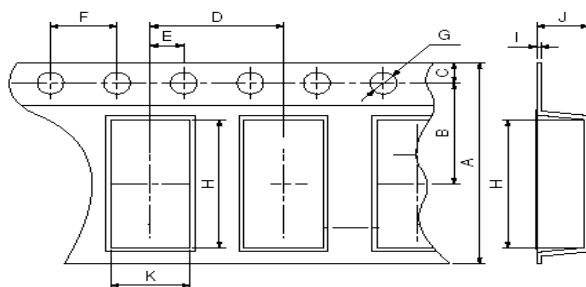
Direction of feed from reel

Option TU



Direction of feed from reel

Tape dimensions



Dimension No.	A	B	C	D	E	F
Dimension(mm)	16.00±0.3	7.5±0.1	1.75±0.1	8.0±0.1	2.0±0.1	4.0±0.1
Dimension No.	G	H	I	J	K	
Dimension(mm)	1.5±0.1/-0	10.4±0.1	0.4±0.05	4.55±0.1	5.1±0.1	

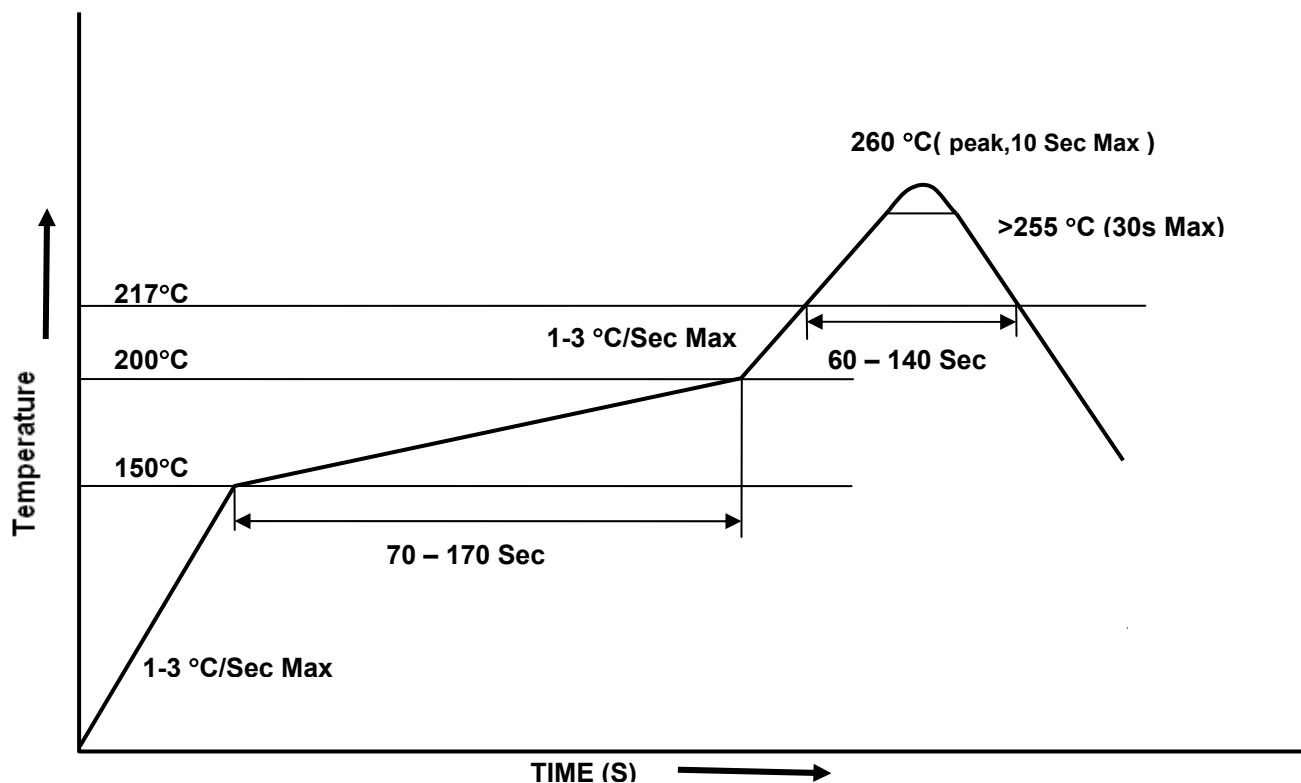


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Solder Reflow Temperature Profile



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